

LMV331W5-7(MS)\LMV393S-13(MS)

Product specification





GENERAL DESCRIPTION

The LMV331W5-7(MS) andLMV393S-13(MS) is the single and dual comparator version, and both are open-drain output comparators for maximum flexibility. It can operate from 2.1V to 5.5V, and have low power consuming 50µA (TYP) per channel at output low.

The LMV331W5-7(MS), LMV393S-13(MS) are themost cost-effective solutions for applications where low voltage operation, low power and space saving are the primary specifications in circuit design for portable consumer products. The LMV331W5-7(MS), LMV393S-13(MS) areavailable in Green SOT-23-5, SOP-8 packages. It operates over an ambient temperature range of -40°C to +85°C.

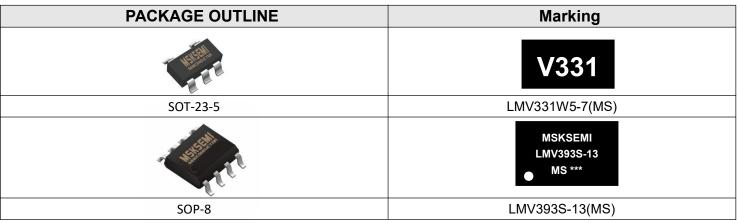
FEATURES

- Supply Range: +2.1V to +5.5V
- Low Supply Current
- 50µA (TYP) per channel at VS = 5V and output low
- Input Common-Mode Voltage Range Includes Ground
- Low Output Saturation Voltage 100mV Typical
- Open-Drain Output for Maximum Flexibility
- SPECIFIED UP TO +125°C
- Micro SIZE PACKAGES: SOT23-5,SOP-8

APPLICATIONS

- Hysteresis Comparators
- Oscillators
- Window Comparators
- Industrial Equipment
- Test and Measurement

Reference News



SIMPLIFIED SCHEMATIC

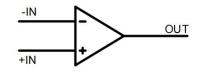


Figure 1. Simplified Schematic

Absolute Maximum Ratings⁽¹⁾

		MIN	MAX	UNIT
	Supply, $V_s=(V+) - (V-)$		7	V
Voltage	Input pin (IN+, IN-) ⁽²⁾	(V-) - 0.3	(V+) + 0.3	V
	Signal output pin ⁽³⁾	(V-) - 0.3	(V+) + 0.3	V
Current	Signal Input pin (IN+, IN-) ⁽²⁾	-10	10	mA
Current	Signal output pin ⁽³⁾	-55	55	mA
	Operating Range	-40	85	°C
Temperature	Storage	-65	150	°C
	Junction		150	°C

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

(2) Output terminals are diode-clamped to the power-supply rails. Output signals that can swing more than 0.5V beyond the supply rails should be current-limited to ±55mA or less.

(3) Short-circuit from output to VCC can cause excessive heating and eventual destruction.

ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	V
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±1000	V

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

Recommended Operating Conditions

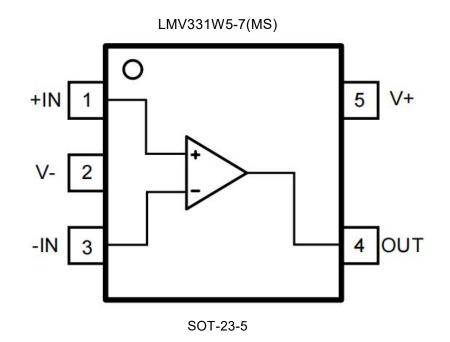
		MIN	MAX	UNIT
Supply voltage $V_{S} = (V_{+}) = (V_{-})$	Single-supply	2.1	5.5	V
Supply voltage , Vs= (V+) - (V-)	Dual-supply	±0.9	±2.75	V



PACKAGE/ORDER INFORMATION

MODEL	OPERATING TEMPERATURE RANGE	PACKAE DESCRIPTION	QTY
LMV331W5-7(MS)	-40°C~85°C	SO-T23-5	3000
LMV393S-13(MS)	-40°C~85°C	SOP-8	2500

Pin Configuration and Functions (Top View)

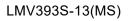


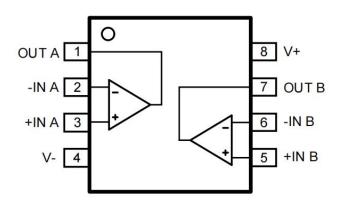
Pin Description

Pin Name	Pin Number SOT23-5	I/O	Description
+IN	1	I	Noninverting input
V-	2	-	Negative(lowest) power supply
-IN	3	I	Inverting input
OUT	4	0	Output
V+	5	-	Positive (highest) power supply



Pin Configuration and Functions (Top View)





SOP-8

Pin Description

Pin Name	Pin Number SOP-8	I/O	Description
OUTA	1	0	Output, channel A
-INA	2	I	Inverting input, channel A
+INA	3	I	Noninverting input, channel A
V-	4	-	Negative(lowest) power supply
+INB	5	I	Noninverting input, channel B
-INB	6	I	Inverting input, channel B
OUTB	7	0	Output, channel B
V+	8	-	Positive (highest) power supply



ELECTRICAL CHARACTERISTICS(Vs = 5.0V)

At $T_A = 25^{\circ}C$, $V_{CM} = V_s/2$, unless otherwise noted.

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
POWER SUPPLY					
Operating Voltage Range		2.1		5.5	V
Quiescent Current/per channel (Output High)			29		μA
Quiescent Current/per channel (Output Low)			50		μA
Power Supply Rejection Ratio	Vs = 2.1V to 5.5V, V _{CM} = Vs/2		70		dB
INPUT					
Input offset voltage		-4	±0.8	4	mV
Input Offset Voltage Drift			0.8		µV/°C
Common-Mode Voltage Range		(V-)-0.1		4.5	V
Common-mode Rejection Ratio	V _{CM} = -0.1V to 4.5V		70		dB
Input Bias Current			2		pА
Input Offset Current			1		pА
OUTPUT		-			
Saturation Voltage	l₀≤4mA		100		mV
Output Pull-up Voltage Range				5.6	V
Output Current(sinking)	V₀≤1.5V		50		mA
SWITCHING					
Dreparation Dalay II To I	R _{PU} =5.1KΩ, Overdrive =10mV		460		
Propagation Delay H To L	R _{PU} =5.1KΩ, Overdrive =100mV		400		
Dran a notion Delay 1 To 11	R _{PU} =5.1KΩ, Overdrive =10mV		950		– ns
Propagation Delay L To H	R _{PU} =5.1KΩ, Overdrive =100mV		850		
Fall Time	R _{PU} =5.1KΩ, Overdrive =100mV		36		ns



ELECTRICAL CHARACTERISTICS(Vs = 2.7V)

$A_t T_A = 25^{\circ}C$, $V_{CM} = V_s/2$, unless otherwise noted.

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
POWER SUPPLY					
Operating Voltage Range		2.1		5.5	V
Quiescent Current/per channel (Output High)			17		μA
Quiescent Current/per channel (Output Low)			30		μA
Power Supply Rejection Ratio	Vs = 2.1V to 5.5V, V _{CM} = Vs/2		70		dB
INPUT					
Input offset voltage		-4	±0.8	4	mV
Input Offset Voltage Drift			0.8		µV/°C
Common-Mode Voltage Range		(V-)-0.1		2.2	V
Common-mode Rejection Ratio	V _{CM} = -0.1V to 2.2V		70		dB
Input Bias Current			2		pА
Input Offset Current			1		pА
OUTPUT		-			
Saturation Voltage	l₀≤4mA		82		mV
Output Pull-up Voltage Range				5.6	V
Output Current(sinking)	V₀≤1.5V		20		mA
SWITCHING		1	1	L	
Propagation Delay H To I	R _{PU} =5.1KΩ, Overdrive =10mV		420		
Propagation Delay H To L	R _{PU} =5.1KΩ, Overdrive =100mV		380		ns
Propagation Delay L To H	R _{PU} =5.1KΩ, Overdrive =10mV		900		
	R _{PU} =5.1KΩ, Overdrive =100mV		880		-
Fall Time	R _{PU} =5.1KΩ, Overdrive =100mV		36		ns



ELECTRICAL CHARACTERISTICS(Vs = 2.1V)

 $A_t T_A = 25^{\circ}C$, $V_{CM} = V_s/2$, unless otherwise noted.

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
POWER SUPPLY					
Operating Voltage Range		2.1		5.5	V
Quiescent Current/per channel (Output High)			15		μA
Quiescent Current/per channel (Output Low)			26		μΑ
Power Supply Rejection Ratio	Vs = 2.1V to 5.5V, V _{CM} = Vs/2		70		dB
INPUT					_
Input offset voltage		-4	±0.8	4	mV
Input Offset Voltage Drift			0.8		µV/°C
Common-Mode Voltage Range		(V-)-0.1		1.3	V
Common-mode Rejection Ratio	V _{CM} = -0.1V to 1.3V		70		dB
Input Bias Current			2		pА
Input Offset Current			1		pА
OUTPUT					
Saturation Voltage	l₀≤4mA		96		mV
Output Pull-up Voltage Range				5.6	V
Output Current(sinking)	V ₀ ≤1.5V		7		mA
SWITCHING				I	
Propagation Delay H To L	R _{PU} =5.1KΩ, Overdrive =10mV		480		
	R _{PU} =5.1KΩ, Overdrive =100mV		430		ns
Propagation Delay L To H	R _{PU} =5.1KΩ, Overdrive =10mV		820		
Propagation Delay L To H	R _{PU} =5.1KΩ, Overdrive =100mV		800		
Fall Time	R _{PU} =5.1KΩ, Overdrive =100mV		38		ns



TYPICAL CHARACTERISTICS

At $T_A = 25^{\circ}C$, $V_S = +5V$, $V_{CM} = V_S/2$, unless otherwise noted.

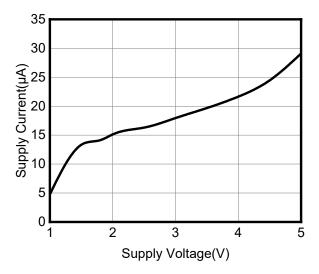


Figure 2. Supply Current vs Supply Voltage Output High

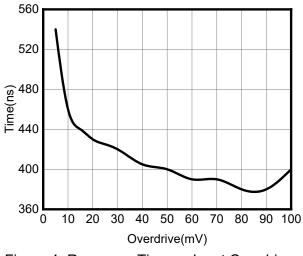


Figure 4. Response Time vs Input Overdrives Negative Transition(V_{CC} =5V)

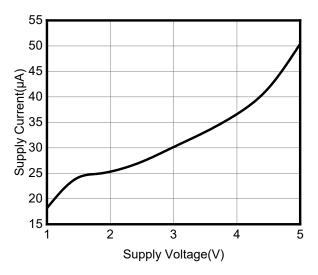
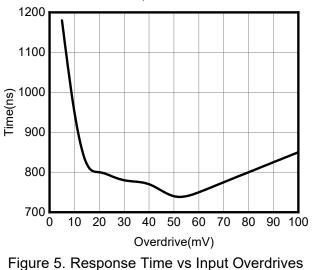


Figure 3. Supply Current vs Supply Voltage Output Low



Positive Transition(V_{CC}=5V)



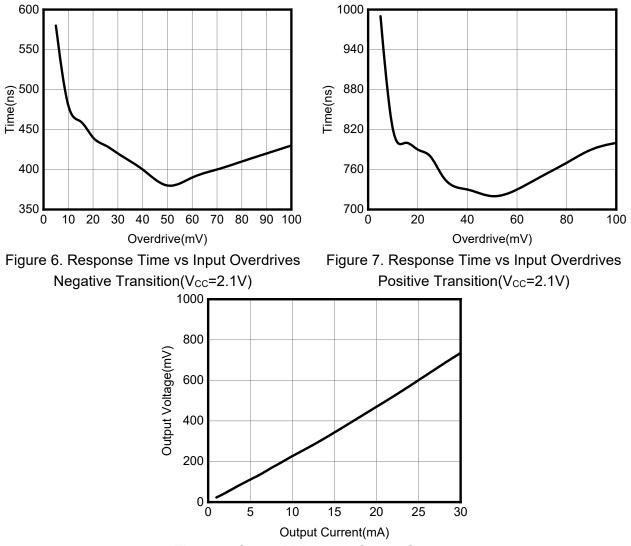


Figure 8. Output Voltage vs Output Current



DETAILED DESCRIPTION

Overview

The LMV331577(MS), LMV393S-13(MS) family of comparators can operate up to 5.5V on the supply pin. This standard device has proven ubiquity and versatility across a wide range of applications.

This is due to its low power and high speed. The opendrain output allows the user to configure the output's logic low voltage (V_{OL}) and can be utilized to enable the comparator to be used in AND functionality.

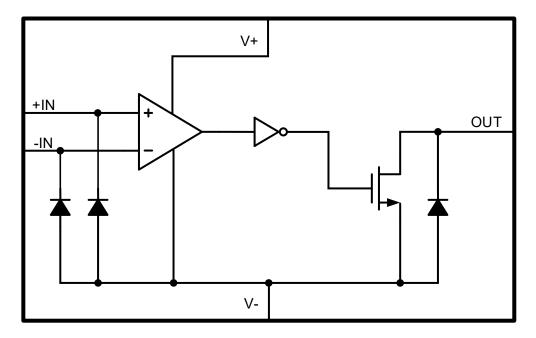


Figure 9. Functional Block Diagram



APPLICATION and IMPLEMENTATION

Application Information

LMV331W5-7(MS), LMV393S-13(MS) will typically be used to compare a single signal to a reference or two signals against each other. Many users take advantage of the open drain output (logic high with pull-up) to drive the comparison logic output to a logic voltage level to an MCU or logic device.

Typical Application

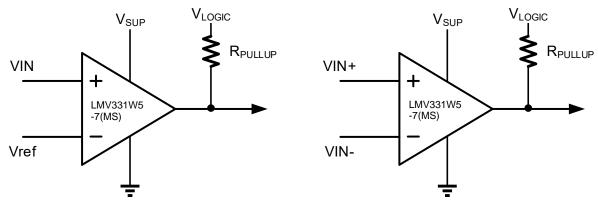


Figure 10. Typical Application Schematic

Power Supply Recommendations

For fast response and comparison applications with noisy or AC inputs, it is recommended to use a bypass capacitor on the supply pin to reject any variation on the supply voltage. This variation causes temporary fluctuations in the comparator's input common mode range and create an inaccurate comparison.

Layout

Layout Guidelines

For accurate comparator applications without hysteresis it is important maintain a stable power supply with minimized noise and glitches, which can affect the high-level input common mode voltage range. In order to achieve this, it is best to add a bypass capacitor between the supply voltage and ground. This should be implemented on the positive power supply and negative supply (if available). If a negative supply is not being used, do not put a capacitor between the IC's GND pin and system ground.

Layout Example

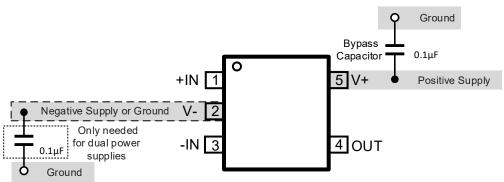
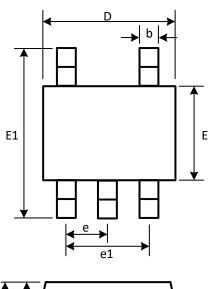


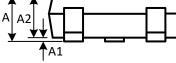
Figure 11. LMV331W5-7(MS) Layout Example

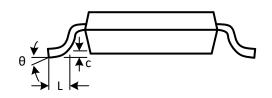


PACKAGE DESCRIPTION

SOT-23-5







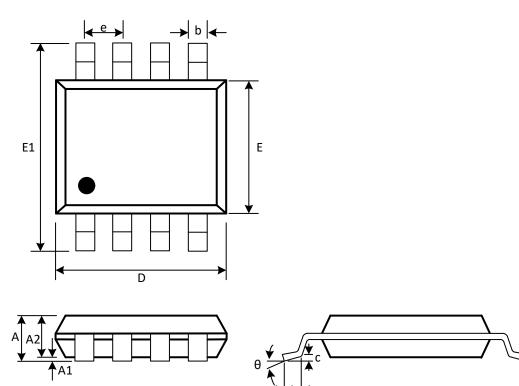
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(Unit: mm		(Uni

Symbol	Min	Max
A	1.050	1.250
A1	0.000	0.100
A2	1.050	1.150
b	0.300	0.500
с	0.100	0.200
D	2.820	3.020
e	0.950	(BSC)
e1	1.800	2.000
E	1.500	1.700
E1	2.650	2.950
L	0.300	0.600
θ	0°	8°



SOP-8

A1 1



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ιu	יווונ.	mm)

Symbol	Min	Max
A	1.350	1.750
A1	0.100	0.250
A2	1.350	1.550
b	0.330	0.510
с	0.170	0.250
D	4.800	5.000
e	1.270(BSC)	
E	3.800	4.000
E1	5.800	6.200
L	0.400	1.270
θ	0°	8°



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